

查询"74HC646D"供应商

FEATURES

- Independent register for A and B buses
- Multiplexed real-time and stored data
- Output capability: bus driver
- I_{CC} category: MSI

GENERAL DESCRIPTION

The 74HC/HCT646 are high-speed Si-gate CMOS devices and are pin compatible with low power Schottky TTL (LSTTL). They are specified in compliance with JEDEC standard no. 7A.

The 74HC/HCT646 consist of bus transceiver circuits with 3-state outputs, D-type flip-flops, and control circuitry arranged for multiplexed transmission of data directly from the internal registers. Data on the "A" or "B" bus will be clocked into the registers as the appropriate clock (CP_{AB} and CP_{BA}) goes to a HIGH logic level. Output enable (\bar{OE}) and direction (DIR) inputs are provided to control the transceiver function. In the transceiver mode, data present at the high-impedance port may be stored in either the "A" or "B" register, or in both. The select source inputs (S_{AB} and S_{BA}) can multiplex stored and real-time (transparent mode) data. The direction (DIR) input determines which bus will receive data when \bar{OE} is active (LOW). In the isolation mode (\bar{OE} = HIGH), "A" data may be stored in the "B" register and/or "B" data may be stored in the "A" register.

(continued on next page)

SYMBOL	PARAMETER	CONDITIONS	TYPICAL		UNIT
			HC	HCT	
t _{PHL} / t _{PLH}	propagation delay A _n , B _n to B _n , A _n	C _L = 15 pF V _{CC} = 5 V	11	13	ns
f _{max}	maximum clock frequency		69	85	MHz
C _I	input capacitance		3.5	3.5	pF
CPD	power dissipation capacitance per channel	notes 1 and 2	30	33	pF

GND = 0 V; T_{amb} = 25 °C; t_r = t_f = 6 ns

Notes

1. CPD is used to determine the dynamic power dissipation (P_D in μ W):

$$P_D = CPD \times V_{CC}^2 \times f_1 + \sum (C_L \times V_{CC}^2 \times f_0) \text{ where:}$$

f_1 = input frequency in MHz C_L = output load capacitance in pF
 f_0 = output frequency in MHz V_{CC} = supply voltage in V
 $\sum (C_L \times V_{CC}^2 \times f_0)$ = sum of outputs

2. For HC, the condition is V_I = GND to V_{CC}.

For HCT the condition is V_I = GND to V_{CC} - 1.5 V

PACKAGE OUTLINES

24-lead DIL; plastic (SOT101A).

24-lead mini-pack; plastic (SO24; SOT137A).

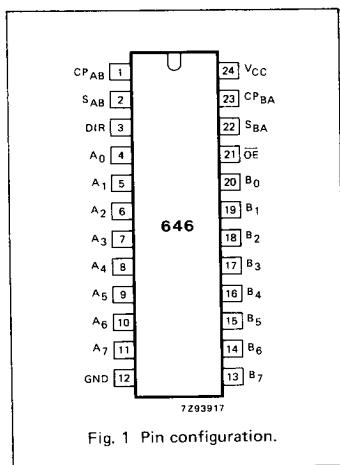


Fig. 1 Pin configuration.

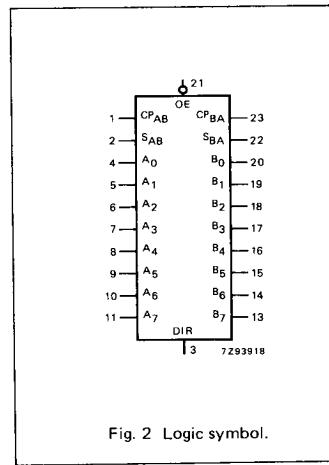


Fig. 2 Logic symbol.

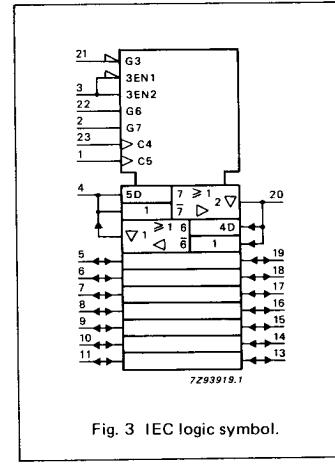


Fig. 3 IEC logic symbol.

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PIN DESCRIPTION

PIN NO.	SYMBOL	NAME AND FUNCTION
1	CPAB	A to B clock input (LOW-to-HIGH, edge-triggered)
2	SAB	select A to B source input
3	DIR	direction control input
4, 5, 6, 7, 8, 9, 10, 11	A ₀ to A ₇	A data inputs/outputs
12	GND	ground (0 V)
20, 19, 18, 17, 16, 15, 14, 13	B ₀ to B ₇	B data inputs/outputs
21	OE	output enable input (active LOW)
22	SBA	select B to A source input
23	CPBA	B to A clock input (LOW-to-HIGH, edge-triggered)
24	V _{CC}	positive supply voltage

GENERAL DESCRIPTION

When an output function is disabled, the input function is still enabled and may be used to store and transmit data. Only one of the two buses, A or B, may be driven at a time. The "646" is functionally identical to the "648", but has non-inverting data paths.

FUNCTION TABLE

OE	DIR	INPUTS		DATA I/O *		FUNCTION		
		CPAB	CPBA	SAB	SBA	A ₀ to A ₇	B ₀ to B ₇	
H	X	H or L ↑	H or L ↑	X	X	input	input	isolation store A and B data
L	L	X	X	X	X	L H	output	real-time B data to A bus stored B data to A bus
L	H	X H or L	X	L H	X X	input	output	real-time A data to B bus stored A data to B bus

* The data output functions may be enabled or disabled by various signals at the OE and DIR inputs. Data input functions are always enabled, i.e., data at the bus inputs will be stored on every LOW-to-HIGH transition on the clock inputs.

H = HIGH voltage level

L = LOW voltage level

X = don't care

↑ = LOW-to-HIGH level transition

Fig. 4 Functional diagram.

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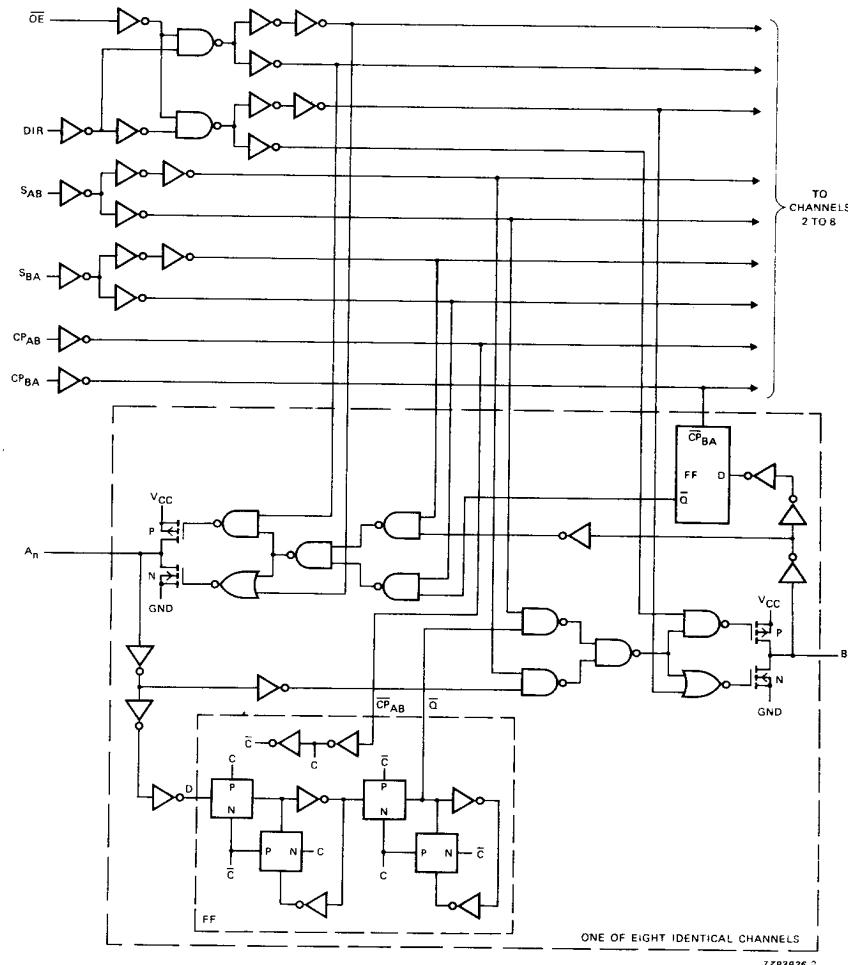


Fig. 5 Logic diagram.

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DC CHARACTERISTICS FOR 74HC

For the DC characteristics see chapter "HCMOS family characteristics", section "Family specifications".

Output capability: bus driver

I_{CC} category: MSI

AC CHARACTERISTICS FOR 74HC

GND = 0 V; t_r = t_f = 6 ns; C_L = 50 pF

SYMBOL	PARAMETER	T _{amb} (°C)						UNIT	TEST CONDITIONS			
		74HC							V _{CC} V	WAVEFORMS		
		+25			−40 to +85		−40 to +125					
		min.	typ.	max.	min.	max.	min.	max.				
t _{PHL} / t _{PLH}	propagation delay A _n ,B _n to B _n ,A _n	39 14 11	135 27 23		170 34 29		205 41 35	ns	2.0 4.5 6.0	Fig. 6		
t _{PHL} / t _{PLH}	propagation delay CP _{AB} ,CP _{BA} to B _n ,A _n	66 24 19	220 44 37		275 55 47		330 66 56	ns	2.0 4.5 6.0	Fig. 7		
t _{PHL} / t _{PLH}	propagation delay S _{AB} ,S _{BA} to B _n ,A _n	55 20 16	190 38 32		240 48 41		285 57 48	ns	2.0 4.5 6.0	Fig. 8		
t _{PZH} / t _{PZL}	3-state output enable time OE to A _n ,B _n	47 17 14	175 35 30		220 44 37		265 53 45	ns	2.0 4.5 6.0	Fig. 9		
t _{PHZ} / t _{PLZ}	3-state output disable time OE to A _n ,B _n	58 21 17	175 35 30		220 44 37		265 53 45	ns	2.0 4.5 6.0	Fig. 9		
t _{PZH} / t _{PZL}	3-state output enable time DIR to A _n ,B _n	50 18 14	175 35 30		220 44 37		265 53 45	ns	2.0 4.5 6.0	Fig. 10		
t _{PHZ} / t _{PLZ}	3-state output disable time DIR to A _n ,B _n	50 18 14	175 35 30		220 44 37		265 53 45	ns	2.0 4.5 6.0	Fig. 10		
t _{THL} / t _{TLH}	output transition time	14 5 4	60 12 10		75 15 13		90 18 15	ns	2.0 4.5 6.0	Figs 6 and 8		
t _W	clock pulse width HIGH or LOW CP _{AB} or CP _{BA}	80 16 14	25 9 7		100 24 20		120 24 20	ns	2.0 4.5 6.0	Fig. 7		
t _{su}	set-up time A _n ,B _n to CP _{AB} ,CP _{BA}	60 12 10	−3 −1 −1		75 15 13		90 18 15	ns	2.0 4.5 6.0	Fig. 7		
t _h	hold time A _n ,B _n to CP _{AB} ,CP _{BA}	35 7 6	6 2 2		45 9 8		55 11 9	ns	2.0 4.5 6.0	Fig. 7		
f _{max}	maximum clock pulse frequency	6.0 30 35	21 63 75		4.8 24 28		4.0 20 24	MHz	2.0 4.5 6.0	Fig. 7		

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DC CHARACTERISTICS FOR 74HCT

For the DC characteristics see chapter "HCMOS family characteristics", section "Family specifications".

Output capability: bus driver
I_{CC} category: MSI

Note to HCT types

The value of additional quiescent supply current (ΔI_{CC}) for a unit load of 1 is given in the family specifications.
To determine ΔI_{CC} per input, multiply this value by the unit load coefficient shown in the table below.

INPUT	UNIT LOAD COEFFICIENT	INPUT	UNIT LOAD COEFFICIENT
S _{A0} , S _{B0} A ₀ to A ₇ and B ₀ to B ₇	0.60 0.75	CP _{AB} , CP _{BA} OE DIR	1.50 1.50 1.25

AC CHARACTERISTICS FOR 74HCT

GND = 0 V; t_r = t_f = 6 ns; C_L = 50 pF

SYMBOL	PARAMETER	T _{amb} (°C)						UNIT	TEST CONDITIONS			
		74HCT							V _{CC} V	WAVEFORMS		
		+25			−40 to +85		−40 to +125					
		min.	typ.	max.	min.	max.	min.	max.				
t _{PHL} / t _{PLH}	propagation delay A _n , B _n to B _n , A _n		16	30		38		45	ns	4.5	Fig. 6	
t _{PHL} / t _{PLH}	propagation delay CP _{AB} , CP _{BA} to B _n , A _n		23	44		55		66	ns	4.5	Fig. 7	
t _{PHL} / t _{PLH}	propagation delay S _{A0} , S _{B0} to B _n , A _n		26	46		58		69	ns	4.5	Fig. 8	
t _{PZH} / t _{PZL}	3-state output enable time OE to A _n , B _n		21	40		50		60	ns	4.5	Fig. 9	
t _{PHZ} / t _{PZL}	3-state output disable time OE to A _n , B _n		20	35		44		53	ns	4.5	Fig. 9	
t _{PZH} / t _{PZL}	3-state output enable time DIR to A _n , B _n		21	40		50		60	ns	4.5	Fig. 10	
t _{PHZ} / t _{PZL}	3-state output disable time DIR to A _n , B _n		21	35		44		53	ns	4.5	Fig. 10	
t _{THL} / t _{TLH}	output transition time		5	12		15		18	ns	4.5	Figs 6 and 8	
t _W	clock pulse width HIGH or LOW CP _{AB} or CP _{BA}	16	8		20		24		ns	4.5	Fig. 7	
t _{su}	set-up time A _n , B _n to CP _{AB} , CP _{BA}	12	3		15		18		ns	4.5	Fig. 7	
t _h	hold time A _n , B _n to CP _{AB} , CP _{BA}	5	1		5		5		ns	4.5	Fig. 7	
f _{max}	maximum clock pulse frequency	30	77		24		20		MHz	4.5	Fig. 7	

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AC WAVEFORMS

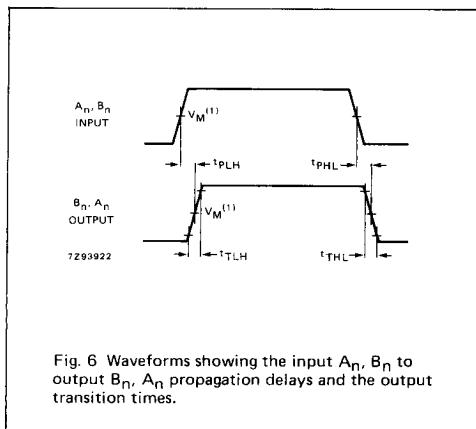


Fig. 6 Waveforms showing the input A_n, B_n to output B_n, A_n propagation delays and the output transition times.

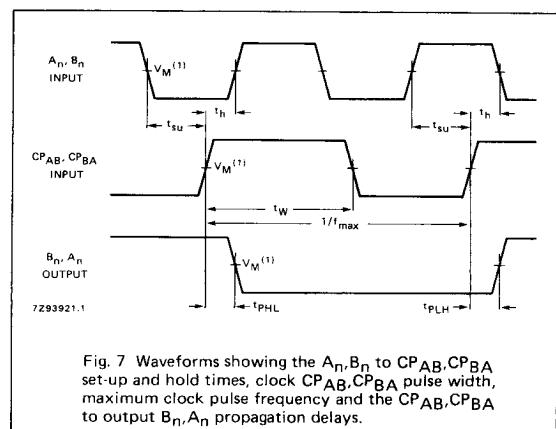


Fig. 7 Waveforms showing the A_n, B_n to CP_{AB}, CP_{BA} set-up and hold times, clock CP_{AB}, CP_{BA} pulse width, maximum clock pulse frequency and the CP_{AB}, CP_{BA} to output B_n, A_n propagation delays.

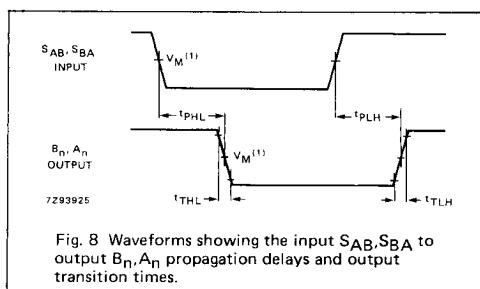


Fig. 8 Waveforms showing the input S_{AB}, S_{BA} to output B_n, A_n propagation delays and output transition times.

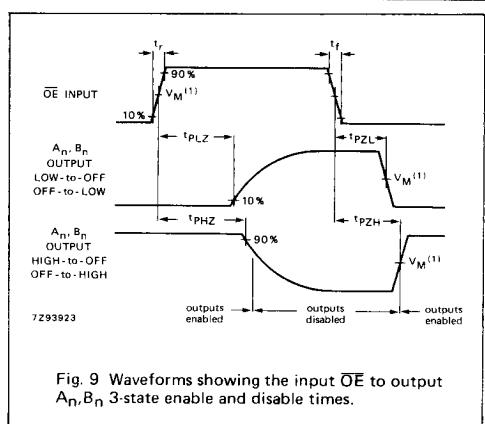


Fig. 9 Waveforms showing the input \bar{OE} to output A_n, B_n 3-state enable and disable times.

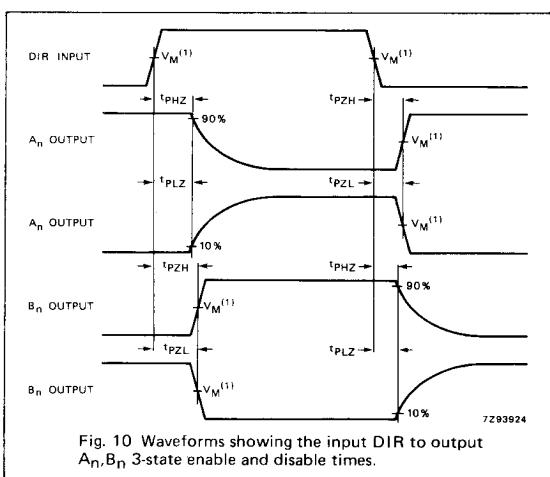


Fig. 10 Waveforms showing the input DIR to output A_n, B_n 3-state enable and disable times.

Note to AC waveforms

- (1) HC : $V_M = 50\%$; $V_I = GND$ to V_{CC} .
- HCT: $V_M = 1.3 V$; $V_I = GND$ to $3 V$.

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APPLICATION INFORMATION
